

# 2N5484 thru 2N5486

CASE 29-05, STYLE 5  
TO-92 (TO-226AA)

JFET  
VHF/UHF AMPLIFIER  
N-CHANNEL — DEPLETION

## MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Gate Voltage	V <sub>DG</sub>	25	Vdc
Reverse Gate-Source Voltage	V <sub>GSR</sub>	25	Vdc
Drain Current	I <sub>D</sub>	30	mAdc
Forward Gate Current	I <sub>G(f)</sub>	10	mAdc
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	310 2.82	mW mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C

Refer to 2N4416 for graphs.

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
----------------	--------	-----	-----	-----	------

### OFF CHARACTERISTICS

Gate-Source Breakdown Voltage (I <sub>G</sub> = -1.0 μAdc, V <sub>DS</sub> = 0)	V <sub>(BR)GSS</sub>	-25	—	—	Vdc
Gate Reverse Current (V <sub>GS</sub> = -20 Vdc, V <sub>DS</sub> = 0) (V <sub>GS</sub> = -20 Vdc, V <sub>DS</sub> = 0, T <sub>A</sub> = 100°C)	I <sub>GSS</sub>	—	—	-1.0 -0.2	nAdc μAdc
Gate Source Cutoff Voltage (V <sub>DS</sub> = 15 Vdc, I <sub>D</sub> = 10 nAdc)	V <sub>GS(off)</sub>	-0.3 -0.5 -2.0	—	-3.0 -4.0 -6.0	Vdc

### ON CHARACTERISTICS

Zero-Gate-Voltage Drain Current (V <sub>DS</sub> = 15 Vdc, V <sub>GS</sub> = 0)	I <sub>DSS</sub>	1.0 4.0 8.0	—	5.0 10 20	mAdc
--	------------------	-------------------	---	-----------------	------

### SMALL-SIGNAL CHARACTERISTICS

Forward Transfer Admittance (V <sub>DS</sub> = 15 Vdc, V <sub>GS</sub> = 0, f = 1.0 kHz)	y <sub>fs</sub>	3000 3500 4000	—	6000 7000 8000	μmhos
Input Admittance (V <sub>DS</sub> = 15 Vdc, V <sub>GS</sub> = 0, f = 100 MHz) (V <sub>DS</sub> = 15 Vdc, V <sub>GS</sub> = 0, f = 400 MHz)	Re(y <sub>is</sub> )	—	—	100 1000	μmhos
Output Admittance (V <sub>DS</sub> = 15 Vdc, V <sub>GS</sub> = 0, f = 1.0 kHz)	y <sub>os</sub>	—	—	50 60 75	μmhos
Output Conductance (V <sub>DS</sub> = 15 Vdc, V <sub>GS</sub> = 0, f = 100 MHz) (V <sub>DS</sub> = 15 Vdc, V <sub>GS</sub> = 0, f = 400 MHz)	Re(y <sub>os</sub> )	—	—	75 100	μmhos
Forward Transconductance (V <sub>DS</sub> = 15 Vdc, V <sub>GS</sub> = 0, f = 100 MHz)	Re(y <sub>fs</sub> )	2500	—	—	μmhos
(V <sub>DS</sub> = 15 Vdc, V <sub>GS</sub> = 0, f = 400 MHz)		3000 3500	—	—	

## 2N5484 thru 2N5486

### ELECTRICAL CHARACTERISTICS (continued) ( $T_A = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
Input Capacitance ( $V_{DS} = 15\text{ Vdc}$ , $V_{GS} = 0$ , $f = 1.0\text{ MHz}$ )	$C_{iss}$	—	—	5.0	pF
Reverse Transfer Capacitance ( $V_{DS} = 15\text{ Vdc}$ , $V_{GS} = 0$ , $f = 1.0\text{ MHz}$ )	$C_{rss}$	—	—	1.0	pF
Output Capacitance ( $V_{DS} = 15\text{ Vdc}$ , $V_{GS} = 0$ , $f = 1.0\text{ MHz}$ )	$C_{oss}$	—	—	2.0	pF

### FUNCTIONAL CHARACTERISTICS

<b>Noise Figure</b> $(V_{DS} = 15\text{ Vdc}$ , $V_{GS} = 0$ , $R_G = 1.0\text{ Megohm}$ , $f = 1.0\text{ kHz}$ ) $(V_{DS} = 15\text{ Vdc}$ , $I_D = 1.0\text{ mAdc}$ , $R_G = 1.0\text{ k ohm}$ , $f = 100\text{ MHz}$ ) $(V_{DS} = 15\text{ Vdc}$ , $I_D = 1.0\text{ mAdc}$ , $R_G = 1.0\text{ k ohm}$ , $f = 200\text{ MHz}$ ) $(V_{DS} = 15\text{ Vdc}$ , $I_D = 4.0\text{ mAdc}$ , $R_G = 1.0\text{ k ohm}$ , $f = 100\text{ MHz}$ ) $(V_{DS} = 15\text{ Vdc}$ , $I_D = 4.0\text{ mAdc}$ , $R_G = 1.0\text{ k ohm}$ , $f = 400\text{ MHz}$ )	NF  2N5484  2N5484  2N5485, 2N5486  2N5485, 2N5486	— — — — —	— — 4.0 — —	2.5 3.0 — 2.0 4.0	dB
<b>Common Source Power Gain</b> $(V_{DS} = 15\text{ Vdc}$ , $I_D = 1.0\text{ mAdc}$ , $f = 100\text{ MHz}$ ) $(V_{DS} = 15\text{ Vdc}$ , $I_D = 1.0\text{ mAdc}$ , $f = 200\text{ MHz}$ ) $(V_{DS} = 15\text{ Vdc}$ , $I_D = 4.0\text{ mAdc}$ , $f = 100\text{ MHz}$ ) $(V_{DS} = 15\text{ Vdc}$ , $I_D = 4.0\text{ mAdc}$ , $f = 400\text{ MHz}$ )	Gps  2N5484  2N5485, 2N5486  2N5485, 2N5486	16 — 18 10	— 14 — —	25 — 30 20	dB